

T-51-10-08

ADC0811 8-Bit Serial I/O A/D Converter With 11-Channel Multiplexer

General Description

The ADC0811 is an 8-Bit successive approximation A/D converter with simultaneous serial I/O. The serial input controls an analog multiplexer which selects from 11 input channels or an internal half scale test voltage.

An input sample-and-hold is implemented by a capacitive reference ladder and sampled data comparator. This allows the input signal to vary during the conversion cycle.

Separate serial I/O and conversion clock inputs are provided to facilitate the interface to various microprocessors.

Features

- Separate asynchronous converter clock and serial data I/O clock.
- 11-Channel multiplexer with 4-Bit serial address logic.
- Built-in sample and hold function. **Connection Diagrams**

Dual-In-Line Package

- Ratiometric or absolute voltage referencing.
- No zero or full-scale adjust required.
- Internally addressable test voltage.
- 0V to 5V input range with single 5V power supply.
- TTL/MOS input/output compatible.
- 0.3" standard width 20-pin dip or 20-pin molded chip carrier

Key Specifications

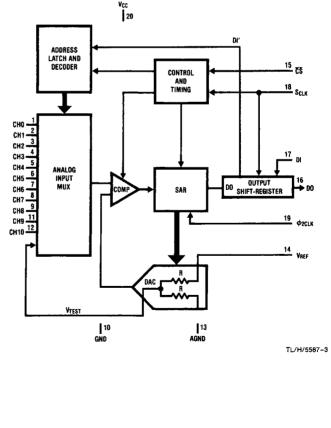
Functional Diagram

- Resolution
- Total unadjusted error ± 1/sLSB and ± 1LSB
- 5V_{DC} Single supply
- 15 mW Low Power
- Conversion Time

32 µS

8-Bits

CHO 20 Феськ ADDRESS LATCH AND CH2 -DECODER CH3 CH4 16 CHS 15 – ČS CHO CH6 14 VRFF 2 CH1 CH7 AGNO CH2 СНЗ CHB 12 -CH10 CH4 ANALOG 6 7 CH5 INPUT MILY CH6 8 CH7 TL/H/5587-1 9 **Top View CH8** 11 CH9 Molded Chip Carrier (PCC) Package CH10 Ø 2CLK Vcc CHO CH9 VTEST CH1 CH₂ CHS TL/H/5587-2 **Top View** Order Number ADC0811J,N,V See NS Packages J20A, N20A, V20A **Use Ordering Information**



Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications. Supply Voltage (V_{CC})

Voltage Inputs and Outputs -0.3V to $V_{CC} + 0.3V$ Input Current Per Pin (Note 3) $\pm 5mA$ Total Package Input Current (Note 3) ±20mA

Storage Temperature -65°C to +150°C Package Dissipation at TA = 25°C 875 mW Lead Temp. (Soldering, 10 seconds) Dual-In-Line Package (plastic) 260°C Dual-In-Line Package (ceramic) 300°C Molded Chip Carrier Package Vapor Phase (60 seconds) 215°C Infrared (15 seconds) 220°C ESD Susceptibility (Note 11) 2000V

Operating Ratings (Notes 1 & 2)

4.5 V_{DC} to 6.0 V_{DC} Supply Voltage (V_{CC}) Temperature Range $T_{MIN} \le T_A \le T_{MAX}$ ADC0811BCN, ADC0811CCN $0^{\circ}C \le T_{A} \le 70^{\circ}C$ ADC0811BCJ, ADC0811BCV -40°C≤T_A≤85°C ADC0811CCJ, ADC0811CCV $-40^{\circ}C \le T_A \le 85^{\circ}C$ ADC0811BJ, ADC0811CJ -55°C≤T_A≤125°C

Electrical Characteristics

The following specifications apply for $V_{CC} = 4.75V$ to 5.25V, $V_{REF} = +4.6V$ to $(V_{CC} + 0.1V)$, $\phi_{2.CLK} = 2.097$ MHz unless otherwise specified. Boldface limits apply from T_{MIN} to T_{MAX} ; all other limits $T_A = T_J = 25^{\circ}C$.

			811BCJ, ADC(811CCJ, ADC(ADC0811BCN, ADC0811BCV ADC0811CCN, ADC0811CCV			
Parameter	Conditions	Typical (Note 6)	Tested Limit (Note 7)	Design Limit (Note 8)	Typical (Note 6)	Tested Limit (Note 7)	Design Limit (Note 8)	Units
CONVERTER AND MULTIPLEX	ER CHARACTERI	STICS						
Maximum Total Unadjusted Error ADC0811BCN, ADC0811BCV ADC0811BCJ, ADC0811BJ ADC0811CCN, ADC0811CCV ADC0811CCJ, ADC0811CJ	V _{REF} = 5.00 V _{DC} (Note 4)		± ½ ± 1			±½ ±1	± ½ ± 1	LSB LSB LSB LSB
Minimum Reference Input Resistance		8		5	8		5	kΩ
Maximum Reference Input Resistance		8	11		8	11	11	kΩ
Maximum Analog Input Range	(Note 5)		V _{CC} +0.05			V _{CC} +0.05	V _{CC} +0.05	٧
Minimum Analog Input Range			GND-0.05			GND-0.05	GND-0.05	٧
On Channel Leakage Current ADC0811BCJ, CCJ, BCN, CCN, BCV, CCV ADC0811CJ, BJ	On Channel = 5V Off Channel = 0V		1000			400	1000	nA nA
ADC0811BCJ, CCJ, BCN, CCN, BCV, CCV ADC0811BJ, CJ	On Channel = 0V Off Channel = 5V (Note 9)		- 1000 - 1000			-400	- 1000	nA nA
Off Channel Leakage Current ADC0811BCJ, CCJ, BCN, CCN, BCV, CCV ADC0811CJ, BJ	On Channel = 5V Off Channel = 0V		- 1000 1000			- 400	1000	nA nA
ADC0811BCJ, CCJ, BCN, CCN, BCV, CCV ADC0811BJ, CJ	On Channel = 0V Off Channel = 5V (Note 9)		1000			400	1000	nA nA
Minimum V _{TEST} Internal Test Voltage	V _{REF} = V _{CC} , CH 11 Selected		125			125	125	(Note 10) Counts
Maximum V _{TEST} Internal Test Voltage	V _{REF} = V _{CC} , CH 11 Selected		130			130	130	(Note 10) Counts

Electrical Characteristics

The following specifications apply for $V_{CC}=4.75V$ to 5.25V, $V_{REF}=+4.6V$ to $(V_{CC}+0.1V)$, $\varphi_{2.CLK}=2.097$ MHz unless otherwise specified. Boldface limits apply from T_{MIN} to T_{MAX} ; all other limits $T_A=T_J=25^{\circ}C$. (Continued)

			I 1BCJ, ADC I 1CCJ, ADC		ADC0811BCN, ADC0811BCV ADC0811CCN, ADC0811CCV]
Parameter	Conditions	Typical (Note 6)	Tested Limit (Note 7)	Design Limit (Note 8)	Typical (Note 6)	Tested Limit (Note 7)	Design Limit (Note 8)	Units
DIGITAL AND DC CHARACTERI	STICS							
V _{IN(1)} , Logical "1" Input Voltage (Min)	V _{CC} =5.25V		2.0			2.0	2.0	٧
V _{IN(0)} , Logical "0" Input Voltage (Max)	V _{CC} =4.75V		0.8			0.8	8.0	٧
I _{IN(1)} , Logical "1" Input Current (Max)	V _{IN} =5.0V	0.005	2.5		0.005	2.5	2.5	μА
I _{IN(0)} , Logical "0" Input Current (Max)	V _{IN} =0V	-0.005	- 2.5		-0.005	2.5	-2.5	μА
V _{OUT(1)} , Logical "1" Output Voltage (Min)	V _{CC} =4.75V I _{OUT} = -360 μA I _{OUT} = -10 μA		2.4 4.5			2.4 4.5	2.4 4.5	V V
V _{OUT(0)} , Logical "0" Output Voltage (Max)	V _{CC} =5.25V I _{OUT} =1.6 mA		0.4			0.4	0.4	٧
I _{OUT} , TRI-STATE Output Current (Max)	V _{OUT} =0V V _{OUT} =5V	0.01 0.01	-3 3		-0.01 0.01	3 3	- 3 3	μA μA
I _{SOURCE} , Output Source Current (Min)	V _{OUT} =0V	-12	-6.5		-14	-6.5	-6.5	mA
I _{SINK} , Output Sink Current (Min)	V _{OUT} =V _{CC}	18	8.0	,	16	8.0	8.0	mA
I _{CC} , Supply Current (Max)	CS=1, V _{REF} Open	1	2.5		1	2.5	2.5	mA
I _{REF} (Max)	V _{REF} =5V	0.7	1		0.7	1	1	mA

AC CHARACTERISTICS

Parameter		Conditions	Tested Typical Limit (Note 6) (Note 7)		Design Limit (Note 8)	Units	
φ _{2 CLK} , φ ₂ Clock Frequency	MIN		0.70		1.0	MHz	
	MAX		3.0	2.0	2.1		
S _{CLK} , Serial Data Clock	MIN			5.0	5.0	KHz	
Frequency	MAX		700	525	525		
T _C , Conversion Process Time	MIN	Not Including MUX Addressing and	48		48	φ ₂ cycles	
	MAX	Analog Input Sampling Times	64		64		
t _{ACC} , Access Time Delay From CS	MIN				1	φ ₂ cycles	
Falling Edge to DO Data Valid	MAX				3		
t _{SET-UP} , Minimum Set-up Time of CS Falling Edge to S _{CLK} Rising Edge					4/\$\psi_2CLK + \frac{1}{2 \S_{CLK}}	sec	
t _H ੁਨਤ, <mark>CS</mark> Hold Time After the Falling Edge of S _{CLK}					0	ns	
t टुड, Total CS Low Time	MIN				t _{set-up} + 8/S _{CLK}	sec	
	MAX				t ॡs(min) + 48/∳2¢LK	sec	
t _{HDI} , Minimum DI Hold Time from S _{CLK} Rising Edge			0		0	ns	
t _{HDO} , Minimum DO Hold Time from S _{CLK} Falling Edge		R _L =30k, C _L =100 pF			10	ns	

Electrical Characteristics

The following specifications apply for $V_{CC}=4.75V$ to 5.25V, $V_{REF}=+4.6V$ to $(V_{CC}+0.1V)$, $\phi_{2\ CLK}=2.097$ MHz unless otherwise specified. **Boldface limits apply from T_{MIN} to T_{MAX};** all other limits $T_A=T_J=25^{\circ}C$. (Continued)

Parameter		Conditions	Typical (Note 6)	Tested Limit (Note 7)	Design Limit (Note 8)	Units
AC CHARACTERISTICS (Continued)						
t _{SDI} , Minimum DI Set-up Time to S _{CLK} Rising Edge			200		400	ns
t _{DDO} , Maximum Delay From S _{CLK} Falling Edge to DO Data Valid	R _L =30k, C _L =100 pF		180	400	400	ns
t _{TRI} , Maximum DO Hold Time, (ĈŜ Rising edge to DO TRI-STATE)	R _L =3k, C _L =100 pF		90	150	150	ns
t _{CA} , Analog Sampling Time	After Addres	s Is Latched			4/S _{CLK} +1 μs	sec
t _{RDO} , Maximum DO	$R_L = 30 \text{ k}\Omega$,	"TRI-STATE" to "HIGH" State	75	150	150	
Rise Time	C _L = 100 pf	"LOW" to "HIGH" State	150	300	300	ns
t _{FDO} , Maximum DO	m DO $R_L=30 \text{ k}\Omega$, "TRI-STATE" to "LOW" Sta		75	150	150	
Fall Time	C _L = 100 pf	"HIGH" to "LOW" State	150	300	300	ns
C _{IN} , Maximum Input	Analog Input	Analog Inputs, ANO-AN10 and VREF			55	
Capacitance	All Others		5		15	ρF

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. DC and AC electrical specifications do not apply when operating the device beyond its specified operating conditions.

Note 2: All voltages are measured with respect to ground.

Note 3: Under over voltage conditions (V_{IN} <0V and V_{IN} > V_{CC}) the maximum input current at any one pin is ± 5 mA. If the voltage at more than one pin exceeds V_{CC} + .3V the total package current must be limited to 20 mA. For example the maximum number of pins that can be over driven at the maximum current level of ± 5 mA is four.

Note 4: Total unadjusted error includes offset, full-scale, linearity, multiplexer, and hold step errors.

Note 5: Two on-chip diodes are tied to each analog input, which will forward-conduct for analog input voltages one diode drop below ground or one diode drop greater than V_{CC} supply. Be careful during testing at low V_{CC} levels (4.5V), as high level analog inputs (5V) can cause this input diode to conduct, especially at elevated temperatures, and cause errors for analog inputs near full-scale. The spec allows 50 mV forward bias of either diode. This means that as long as the analog V_{III} does not exceed the supply voltage by more than 50 mV, the output code will be correct. To achieve an absolute 0 V_{DC} to 5 V_{DC} input voltage range will therefore require a minimum supply voltage of 4.950 V_{DC} over temperature variations, initial tolerance and loading.

Note 6: Typicals are at 25°C and represent most likely parametric norm.

Note 7: Guaranteed and 100% production tested under worst case condition.

Note 8: Guaranteed, but not 100% production tested. These limits are not used to calculate outgoing quality levels.

Note 9: Channel leakage current is measured after the channel selection.

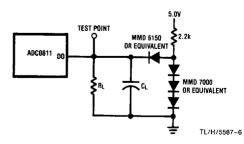
Note 10: 1 count = V_{REF}/256.

Note 11: Human body model, 100 pF discharged through a 1.5 k Ω resistor.

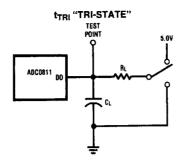
Test Circuits

Leakage Current TL/H/5587-17

D0 Except "TRI-STATE"

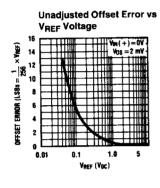


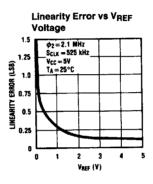
Test Circuits (Continued)

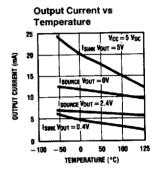


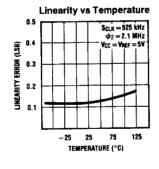
TL/H/5587-22

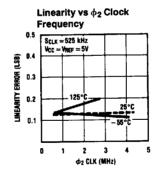
Typical Performance Characteristics

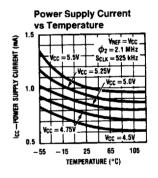


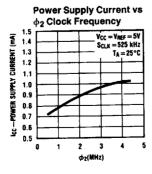


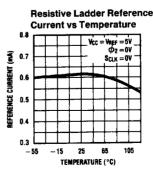






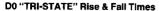


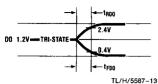


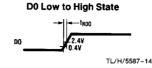


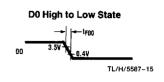
TL/H/5587-16

Timing Diagrams



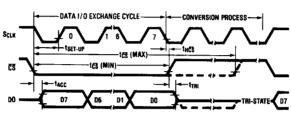






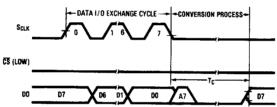
TL/H/5587-11

Timing with a continuous S_{CLK}



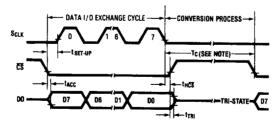
*Strobing CS High and Low will abort the present conversion and initiate a new serial I/O exchange

Timing with a gated S_{CLK} and CS Continuously Low



TL/H/5587-9

Using $\overline{\text{CS}}$ To TRI-STATE D0

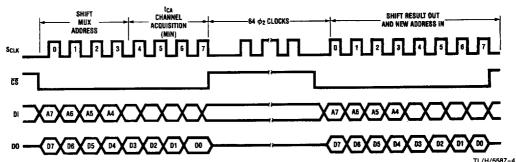


Note: Strobing $\overline{\text{CS}}$ Low during this time interval will abort the conversion in process.

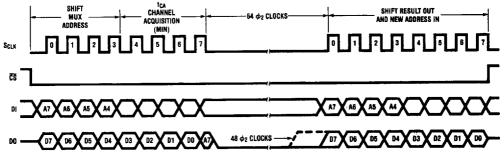
TL/H/5587-10

Timing Diagrams (Continued)

CS High During Conversion



CS Low During Conversion



TL/H/5587-5

Note: DO and DI lines share the 8-bit I/O shift register(see Functional Block Diagram). Since the MUX address bits are shifted in on SCLK rising edges while SCLK falling edges shift out conversion data on DO, the eighth falling edge of S_{CLK} will shift out the MSB MUX address bit (A7) on DO. Thus, if addressing channels CH8-CH10, a high DO will occur momentarily (one ϕ_2 clock period) until the 8-bit I/O shift register is cleared by the internal EOC signal.

Channel Addressing Table

TABLE I. ADC 0811 Channel Addressing

	MUX ADDRESS					ANALOG CHANNEL		
A7	A ₆	A ₅	A ₄	A ₃	A ₂	Αı	AQ	SELECTED
0	0	0	0	Х	Х	Х	х	CH0
0	0	0	1	Х	X	Х	X	CH1
0	0	1	0	Х	X	Х	X	CH2
0	0	1	1	Х	Ιx	X	Х	CH3
0	1	0	0	Х	X	x	Х	CH4
0	1	0	1	Х	Ιx	X	X	CH5
0	1	1	0	Х	Ιx	X	X	CH6
0	1	1	1	Х	X	Х	X	CH7
1	0	0	0	Х	X	Х	Х	CH8
1	0	0	1		Х	Х	Х	CH9
1	0	1	0	X X	X	Х	Х	CH10
1	0	1	1	X	X	Х	Х	V _{TEST}
1	1	Х	X	Х	Х	Х	Х	LOGIC TEST MODE*

^{*} Analog channel inputs CH0 thru CH3 are logic outputs

ADC0811

2-107

Functional Description

1.0 DIGITAL INTERFACE

The ADC0811 uses five input/output pins to implement the serial interface. Taking chip select (CS) low enables the I/O data lines (DO and DI) and the serial clock input (S_{CLK}). The result of the last conversion is transmitted by the A/D on the DO line, while simultaneously the DI line receives the address data that selects the mux channel for the next conversion. The mux address is shifted in on the rising edge of SCLK and the conversion data is shifted out on the falling edge. It takes eight S_{CLK} cycles to complete the serial I/O. A second clock (ϕ_2) controls the SAR during the conversion process and must be continuously enabled.

1.1 CONTINUOUS SCIK

With a continuous S_{CLK} input CS must be used to synchronize the serial data exchange (see Figure 1). The ADC0811 recognizes a valid CS one to three φ₂ clock periods after the actual falling edge of CS. This is implemented to ensure noise immunity of the CS signal. Any spikes on CS less than one ϕ_2 clock period will be ignored. $\overline{\text{CS}}$ must remain low during the complete I/O exchange which takes eight S_{CLK} cycles. Although CS is not immediately acknowledged for the purpose of starting a new conversion, the falling edge of CS immediately enables DO to output the MSB (D7) of the previous conversion.

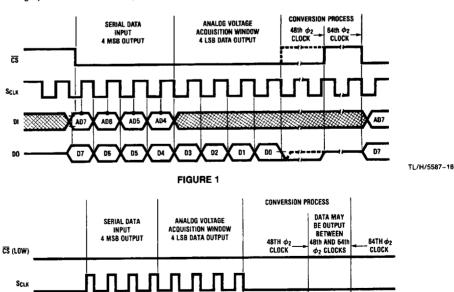
The first S_{CLK} rising edge will be acknowledged after a setup time (t_{set-up}) has elapsed from the falling edge of \overline{CS} . This and the following seven S_{CLK} rising edges will shift in the channel address for the analog multiplexer. Since there are 12 channels only four address bits are utilized. The first four S_{CLK} cycles clock in the mux address, during the next four S_{CLK} cycles the analog input is selected and sampled. During this mux address/sample cycle, data from the last conversion is also clocked out on DO. Since D7 was clocked out on the falling edge of CS only data bits D6-D0 remain to be received. The following seven falling edges of SCLK shift out this data on DO.

The 8th S_{CLK} falling edge initiates the beginning of the A/D's actual conversion process which takes between 48 to 64 Φ2 cycles (T_C). During this time CS can go high to TRI-STATE DO and disable the S_{CLK} input or it can remain low. If CS is held low a new I/O exchange will not start until the conversion sequence has been completed, however once the conversion ends serial I/O will immediately begin. Since there is an ambiguity in the conversion time (T_C) synchronizing the data exchange is impossible. Therefore CS should go high before the 48th \$\phi_2\$ clock has elasped and return low after the 64th ϕ_2 to synchronize serial communication.

A conversion or I/O operation can be aborted at any time by strobing \overline{CS} . If \overline{CS} is high or low less than one ϕ_2 clock it will be ignored by the A/D. If the CS is strobed high or low between 1 to 3 ϕ_2 clocks the A/D may or may not respond. Therefore CS must be strobed high or low greater than 3 \$\phi_2\$ clocks to ensure recognition. If a conversion or I/O exchange is aborted while in process the consequent data output will be erroneous until a complete conversion sequence has been implemented.

1.2 DISCONTINUOUS SCI K

Another way to accomplish synchronous serial communication is to tie CS low continuously and disable S_{CLK} after its 8th falling edge (see Figure 2). SCLK must remain low for



TL/H/5587-19

D2 D1 00

D3

ΔR

Đ5

Functional Description (Continued)

at least 64 φ₂ clocks to insure that the A/D has completed its conversion. If SCLK is enabled sooner, synchronizing to the data output on DO is not possible since an end of conversion signal from the A/D is not available and the actual conversion time is not known. With CS low during the conversion time (64 φ₂ max) DO will go low after the eighth falling edge of SCIK and remain low until the conversion is completed. Once the conversion is through DO will transmit the MSB. The rest of the data will be shifted out once SCLK is enabled as discussed previously.

If CS goes high during the conversion sequence DO is tristated, and the result is not affected so long as CS remains high until the end of the conversion.

1.2 MULTIPLEXER ADDRESSING

The four bit mux address is shifted, MSB first, into DI. Input data corresponds to the channel selected as shown in table 1. Care should be taken not to send an address greater than or equal to twelve (11XX) as this puts the A/D in a digital testing mode. In this mode the analog inputs CH0 thru CH3 become digital outputs, for our use in production testing.

2.0 ANALOG INPUT

2.1 THE INPUT SAMPLE AND HOLD

The ADC0811's sample/hold capacitor is implemented in its capacitive ladder structure. After the channel address is received, the ladder is switched to sample the proper analog input. This sampling mode is maintained for 1 µsec after the

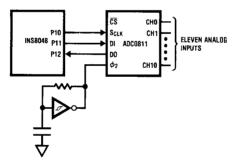
eighth S_{CLK} falling edge. The hold mode is initiated with the start of the conversion process. An acquisition window of $4t_{SCIK}+1$ µsec is therefore available to allow the ladder capacitance to settle to the analog input voltage. Any change in the analog voltage before or after the acquisition window will not effect the A/D conversion result.

In the most simple case, the ladder's acquisition time is determined by the Ron (3K) of the multiplexer switches and the total ladder capacitance (90pf). These values yield an acquisition time of about 2 µsec for a full scale reading. Therefore the analog input must be stable for at least 2 µsec before and 1 μsec after the eighth S_{CLK} falling edge to ensure a proper conversion. External input source resistance and capacitance will lengthen the acquisition time and should be accounted for.

Other conventional sample and hold error specifications are included in the error and timing specs of the A/D. The hold step and gain error sample/hold specs are taken into account in the ADC0811's total unadjusted error, while the hold settling time is included in the A/D's max conversion time of 64 ϕ_2 clock periods. The hold droop rate can be thought of as being zero since an unlimited amount of time can pass between a conversion and the reading of data. However, once the data is read it is lost and another conversion is started.

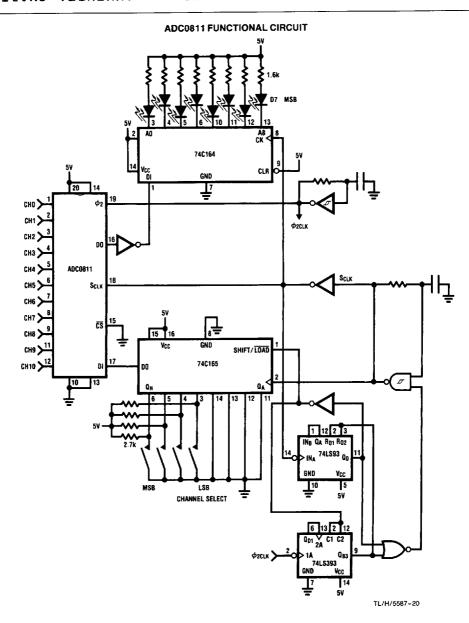
Typical Applications

ADC0811-INS8048 INTERFACE



TL/H/5587~21





Ordering Information

Temperature Range		0°C to 70°C	-40°C to +85°C	-55°C to +125°C ADC0811BJ	
Total ± 1/2 LSB		ADC0811BCN	ADC0811BCJ		
Unadjusted	± /2 LOD	10000110011	ADC0811BCV		
Error	±1 LSB	ADC0811CCN	ADC0811CCJ ADC0811CCV	ADC0811CJ	
Package Outline		N20A	J20A, V20A	J20A	